


PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

MITSUBISHI Nch POWER MOSFET

FY7BCH-02

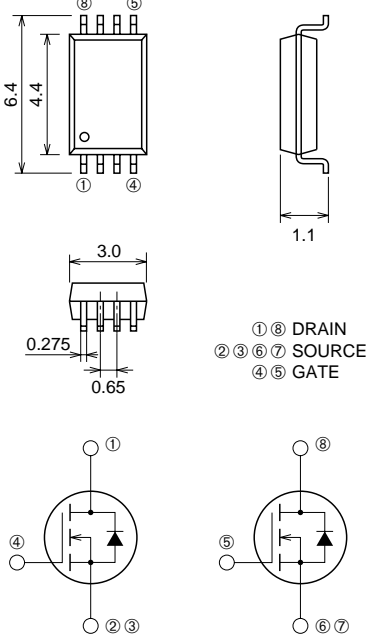
HIGH-SPEED SWITCHING USE

FY7BCH-02



- 2.5V DRIVE
- V_{DSS} 20V
- r_{DS (ON)} (MAX) 27mΩ
- I_D 7A

OUTLINE DRAWING Dimensions in mm



① ⑧ DRAIN
 ② ③ ⑥ ⑦ SOURCE
 ④ ⑤ GATE

TSSOP8

APPLICATION

Motor control, Lamp control, Solenoid control
 DC-DC converter, etc.

MAXIMUM RATINGS (T_c = 25°C)

Symbol	Parameter	Conditions	Ratings	Unit
V _{DSS}	Drain-source voltage	V _{GS} = 0V	20	V
V _{GSS}	Gate-source voltage	V _{DS} = 0V	±10	V
I _D	Drain current		7	A
I _{DM}	Drain current (Pulsed)		49	A
I _{DA}	Avalanche drain current (Pulsed)	L = 10μH	7	A
I _S	Source current		1.5	A
I _{SM}	Source current (Pulsed)		6.0	A
P _D	Maximum power dissipation		1.6	W
T _{ch}	Channel temperature		-55 ~ +150	°C
T _{stg}	Storage temperature		-55 ~ +150	°C
—	Weight	Typical value	0.035	g

PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

ELECTRICAL CHARACTERISTICS (Tch = 25°C)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V (BR) DSS	Drain-source breakdown voltage	Id = 1mA, VGS = 0V	20	—	—	V
IGSS	Gate-source leakage current	VGS = ±10V, VDS = 0V	—	—	±0.1	μA
IDSS	Drain-source leakage current	VDS = 20V, VGS = 0V	—	—	0.1	mA
VGS (th)	Gate-source threshold voltage	Id = 1mA, VDS = 10V	0.4	0.7	1.3	V
rDS (ON)	Drain-source on-state resistance	Id = 7A, VGS = 4V	—	20	27	mΩ
rDS (ON)	Drain-source on-state resistance	Id = 3.5A, VGS = 2.5V	—	29	40	mΩ
VDS (ON)	Drain-source on-state voltage	Id = 7A, VGS = 4V	—	0.140	0.189	V
yfs	Forward transfer admittance	Id = 7A, VDS = 10V	—	15	—	S
Ciss	Input capacitance	VDS = 10V, VGS = 0V, f = 1MHz	—	950	—	pF
Coss	Output capacitance		—	350	—	pF
Crss	Reverse transfer capacitance		—	260	—	pF
td (on)	Turn-on delay time		—	20	—	ns
tr	Rise time	VDD = 10V, Id = 3.5A, VGS = 4V, RGEN = RGS = 50Ω	—	65	—	ns
td (off)	Turn-off delay time		—	135	—	ns
tf	Fall time		—	130	—	ns
VSD	Source-drain voltage		IS = 1.5A, VGS = 0V	—	0.75	1.1
Rth (ch-a)	Thermal resistance	Channel to ambient	—	—	78.1	°C/W
trr	Reverse recovery time	IS = 1.5A, dis/dt = -50A/μs	—	50	—	ns